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The Triply Bonded $\text{Al}\equiv\text{Sb}$ Molecules: A Theoretical Prediction

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Abstract

The effect of substitution on the potential energy surfaces of $\text{RAl}\equiv\text{SbR}$ ($\text{R} = \text{F}, \text{OH}, \text{H}, \text{CH}_3, \text{SiH}_3, \text{SiMe}(\text{Si}t\text{Bu}_3)_2, \text{Si}i\text{PrDis}_2, \text{Tbt}, \text{and Ar}^*$) is investigated using density functional theories (M06-2X/Def2-TZVP, B3PW91/Def2-TZVP, and B3LYP/LANL2DZ + dp). The theoretical results demonstrated that all the triply bonded $\text{RAl}\equiv\text{SbR}$ compounds with small substituents are unstable and can spontaneously rearrange to other doubly bonded isomers. That is, the smaller groups, such as $\text{R} = \text{F}, \text{OH}, \text{H}, \text{CH}_3$ and SiH_3 , neither kinetically nor thermodynamically stabilize the triply bonded $\text{RAl}\equiv\text{SbR}$ compounds. However, the triply bonded $\text{R}'\text{Al}\equiv\text{SbR}'$ molecules that feature bulkier substituents ($\text{R}' = \text{SiMe}(\text{Si}t\text{Bu}_3)_2, \text{Si}i\text{PrDis}_2, \text{Tbt}, \text{and Ar}^*$) are found to possess the global minimum on the singlet potential energy surface and are both kinetically and thermodynamically stable. In particular, the bonding characters of the $\text{R}'\text{Al}\equiv\text{SbR}'$ species agree well with the valence-electron bonding model (model) as well as several theoretical analyses (the natural bond orbital, the natural resonance theory, and the charge decomposition analysis). That is to say, $\text{R}'\text{Al}\equiv\text{SbR}'$ molecules that feature groups are regarded as $\text{R}'-\text{Al}\equiv\text{Sb}-\text{R}'$. Their theoretical evidence shows that both the electronic and the steric effects of bulkier substituent groups play a decisive role in making triply bonded $\text{R}'\text{Al}\equiv\text{SbR}'$ species synthetically accessible and isolable in a stable form.

Keywords: aluminum, antimony, group 13 elements, group 13 elements, triple bond

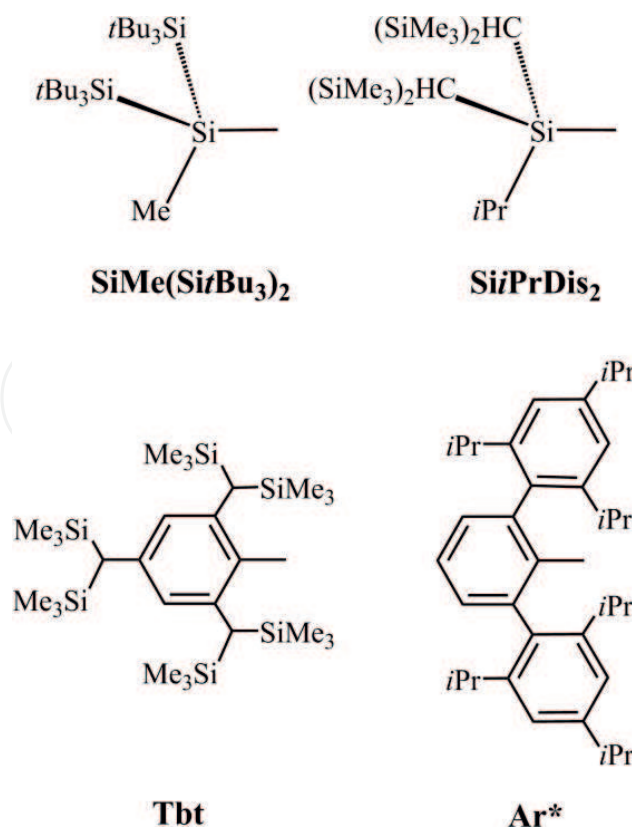
1. Introduction

The chemical synthesis and structural characterization of molecules that feature triple bonds [2] between heavier group 14 elements ($\text{E14} = \text{Si}, \text{Ge}, \text{Sn}$ and Pb) are of interest because of their interesting structural chemistry and their potential applications in organic and inorganic synthesis [1–10]. Although understanding of these $\text{RE14}\equiv\text{E14R}$ molecules that feature heavier

group 14 atoms has increased during the last two decades, the understanding of the $\text{RE13}\equiv\text{E15R}$ compounds, which are isoelectronic to acetylene from a valence electron viewpoint, is still limited. The reason for this limited knowledge of acetylene analogues, $\text{RE13}\equiv\text{E15R}$, could be due to the fact that there has been limited preparation and the isolation of these species in a stable form [11, 12]. Theoretical methods allow a theoretical design of the $\text{RE13}\equiv\text{E15R}$ molecules to be made that increases understanding of their potential properties.

The III-V semiconductors that contain antimony have several important applications in optoelectronic devices that operate in the infrared region and in high-speed devices, which has prompted widespread studies of promising precursor systems for these materials [13]. In particular, the chemical synthesis and structural characterization of AlSb single-source precursors of the type $\text{R}_3\text{Al-SbR}'_3$ has attracted much attention, owing to their importance in CVD procedures [14], which is a developing industry for the production of thin films of the corresponding semiconducting materials [15]. As far as the authors are aware, only a handful of group 13 antimonides that contain Al-Sb σ -bonds have been discovered [16]. No triply bonded $\text{RAl}\equiv\text{SbR}$ species, which is isoelectronic to $\text{HC}\equiv\text{CH}$, has been reported both experimentally and theoretically.

Density functional theory (DFT) is used to determine the structures, the kinetic stability and bonding properties of various $\text{RAl}\equiv\text{SbR}$ triply bonded forms on the singlet ground state, in order to obtain a better understanding of aluminum \equiv antimony triple bonds. This work reports the possible existence of triply bonded $\text{RAl}\equiv\text{SbR}$ molecules, from the viewpoint of the effect of substituents, using DFT [17]. That is, M06-2X/Def2-TZVP, B3PW91/Def2-TZVP



Scheme 1. Four bulky ligands, which are $\text{SiMe}(\text{Si}^t\text{Bu}_3)_2$, $\text{Si}^i\text{PrDis}_2$, Tbt, and Ar^* .

and B3LYP/LANL2DZ + dp are used for small substituents ($\text{R} = \text{H}, \text{F}, \text{OH}, \text{CH}_3$, and SiH_3) and M06-2X/Def2-TZVP [18] for large substituents ($\text{R} = \text{SiMe}(\text{Si}t\text{Bu}_3)_2$, $\text{Si}i\text{PrDis}_2$, Tbt , and Ar^* ; see **Scheme 1**) [19].

2. General considerations

The valence-bond bonding model is a well-known satisfactory method, which is an approximate theory to explain the electron pair or chemical bond by quantum mechanics, for predicting molecular geometries [20]. Two valence-bond bonding models (**Figure 1**) are thus used to interpret the bonding properties of triply bonded $\text{RAl}\equiv\text{SbR}$ species. In model [1], the $\text{RAl}\equiv\text{SbR}$ molecule is partitioned into two units: a singlet $\text{R}-\text{Al}$ and a singlet $\text{R}-\text{Sb}$. In model [2], the $\text{RAl}\equiv\text{SbR}$ compound is divided into two moieties: a triplet $\text{R}-\text{Al}$ and a triplet $\text{R}-\text{Sb}$.

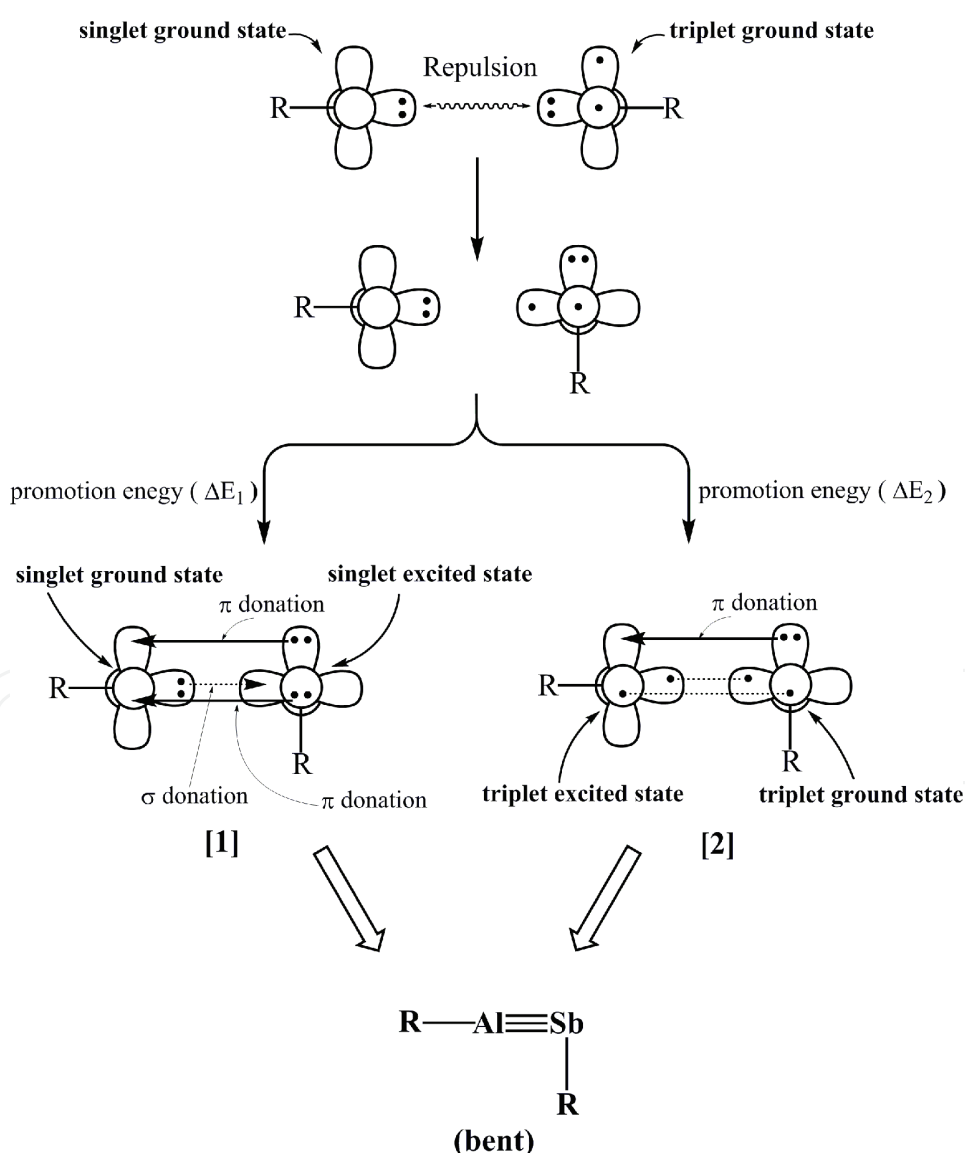


Figure 1. The valence-bond bonding models [1, 2] for the triply bonded $\text{RAl}\equiv\text{SbR}$ molecule.

As a result, the choice of the bonding model that is used to explain the bonding characters of $\text{RAl}\equiv\text{SbR}$ depends on the promotion energies ($\Delta E_{\text{ST}} = E_{\text{triplet}} - E_{\text{singlet}}$) of the $\text{R}-\text{Al}$ and $\text{R}-\text{Sb}$ fragments. According to current theoretical calculations (see below), it is known that $\text{R}-\text{Al}$ occupies the singlet ground state, but $\text{R}-\text{Sb}$ occupies the triplet ground state. In consequence, if the value of ΔE_{ST} for $\text{R}-\text{Al}$ is much larger than that for $\text{R}-\text{Sb}$, the latter easily jumps to the singlet excited state. Hence, model [1] can be used to explain the bonding nature of the $\text{RAl}\equiv\text{SbR}$ molecule. In contrast, if the value of ΔE_{ST} for $\text{R}-\text{Al}$ is smaller than that for $\text{R}-\text{Sb}$, the former is readily promoted to the excited triplet state. Therefore, model [2] is used to interpret the bond constitutions of the $\text{RAl}\equiv\text{SbR}$ compound.

Two points are worthy of note. The first is that since aluminum and antimony respectively belong to group 13 and group 15 and both elements have different atomic radii (covalent radii: 118 pm and 140 for Al and Sb, respectively) [20], the overlapping populations between Al and Sb should not be strong. The second is that the lone pairs of both aluminum and antimony feature the valence s character. This, in turn, makes the overlap integrals between the lone pair orbital and the pure p orbital small. These two factors mean that the triple bond between aluminum and antimony is weak, unlike the traditional triple bond in acetylene.

Bearing the above bonding analyses in mind, theoretical evidences are given in the following sections.

3. Results and discussion

3.1. Small ligands on substituted $\text{RAl}\equiv\text{SbR}$

Five small substituents ($\text{R} = \text{F}, \text{OH}, \text{H}, \text{CH}_3$ and SiH_3) are chosen, which include electronegative and electropositive groups, to determine their stability and bonding properties on the triply bonded $\text{RAl}\equiv\text{SbR}$ molecules using the three types of DFT calculations (i.e., M06-2X/Def2-TZVP, B3PW91/Def2-TZVP and B3LYP/LANL2DZ + dp). **Figure 2** shows the potential energy surfaces of the intra-molecular 1,2-migration reactions for five triply bonded $\text{RAl}\equiv\text{SbR}$ compounds that feature small substituents. That is to say, the triply bonded $\text{RAl}\equiv\text{SbR}$ species can undergo a 1,2-shift to give either $\text{R}_2\text{Al}=\text{Sb}$: or: $\text{Al}=\text{SbR}_2$ doubly bonded isomers.

As seen in **Figure 2**, the three DFT computational results demonstrate that the triply bonded $\text{RAl}\equiv\text{SbR}$ species that feature small substituents are all both kinetically and thermodynamically unstable on the intra-molecular 1,2-migration reaction potential energy surfaces. In other words, once the triply bonded $\text{RAl}\equiv\text{SbR}$ with small substituents is formed, it can easily proceed along the 1,2-migration to give the thermodynamically stable doubly bonded isomer, either $\text{R}_2\text{Al}=\text{Sb}$: or: $\text{Al}=\text{SbR}_2$. The theoretical findings give strong evidence that the triply bonded $\text{RAl}\equiv\text{SbR}$ molecules that feature the small ligands are highly unlikely to be detected experimentally.

Although current theoretical observations show that the formation of $\text{RAl}\equiv\text{SbR}$ involving small ligands is not likely, some of their physical properties, which are shown in **Table 1**, must be theoretically determined in order to design much more stable aluminum \equiv antimony acetylene analogues.

M06-2X/Def2-TZVP
 B3PW91/Def2-TZVP
 B3LYP/LANL2DZ+dp

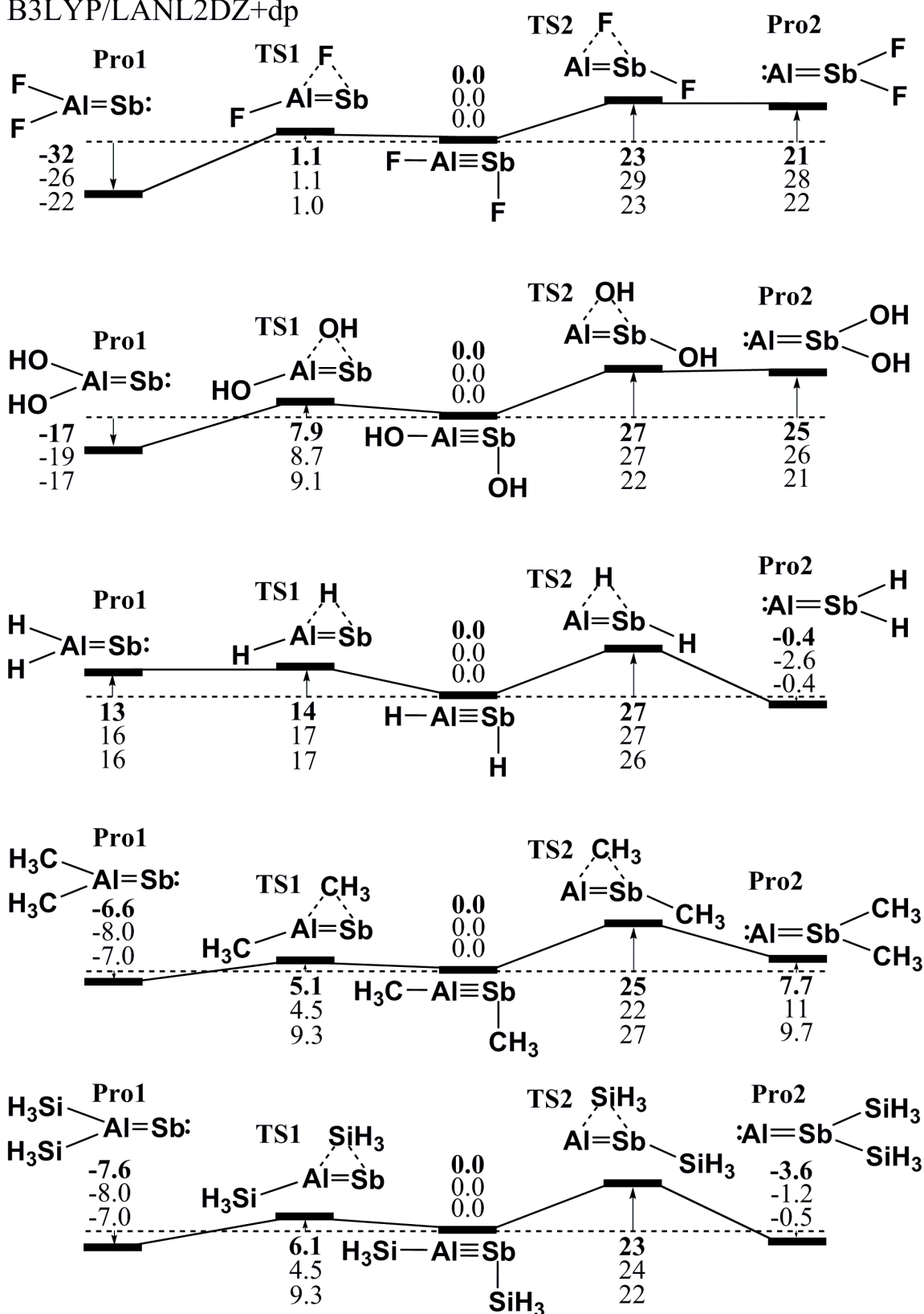


Figure 2. The 1,2-migration energy surfaces for $RAl\equiv SbR$ ($R = H, F, CH_3, OH,$ and SiH_3). These relative Gibbs free energies (kcal/mol) are computed at the M06-2X/Def2-TZVP, B3PW91/Def2-TZVP, and B3LYP/LANL2DZ + dp levels of theory.

R	F	OH	H	CH ₃	SiH ₃
AlαSb (Å)	2.528 (2.536) [2.556]	2.531 (2.518) [2.565]	2.388 (2.397) [2.436]	2.466 (2.462) [2.499]	2.539 (2.524) [2.560]
∠R-Al-Sb (°)	176.8 (176.2) [179.2]	173.4 (172.0) [176.5]	170.7 (167.6) [167.6]	177.7 (173.8) [173.2]	176.8 (176.2) [179.7]
∠Al-Sb-R (°)	88.86 (88.07) [88.53]	86.55 (86.13) [90.43]	82.25 (84.42) [86.43]	94.46 (96.42) [96.75]	88.86 (88.07) [88.53]
∠R-Sb-Al-R (°)	179.9 (179.9) [180.0]	179.7 (176.9) [178.6]	180.0 (180.0) [180.0]	179.6 (179.9) [178.2]	179.9 (179.9) [180.0]
Q _{Al} ¹	0.5201 (0.495) [0.715]	0.418 (0.401) [0.469]	0.164 (0.161) [0.414]	0.291 (0.262) [0.282]	0.208 (0.219) [0.193]
Q _{Sb} ²	0.329 (0.277) [0.217]	0.196 (0.136) [0.119]	−0.134 (−0.107) [−0.032]	−0.054 (−0.018) [−0.134]	−0.198 (−0.100) [−0.179]
ΔE _{ST} for Al-R (kcal/mol) ³	79.78 (71.44) [73.78]	72.05 (65.86) [67.75]	43.73 (40.25) [40.80]	48.75 (42.38) [45.00]	32.87 (29.08) [31.97]
ΔE _{ST} for Sb-R (kcal/mol) ⁴	−32.40 (−28.88) [−27.52]	−25.88 (−21.16) [−20.04]	−33.35 (−29.42) [−27.91]	−31.52 (−27.31) [−26.00]	−30.78 (−25.61) [−25.21]
HOMO-LUMO (kcal/mol)	165.5 (168.4) [167.2]	159.8 (140.1) [145.2]	257.6 (205.2) [277.6]	146.4 (123.3) [129.2]	172.2 (179.5) [177.9]
BE (kcal/mol) ⁵	25.82 (32.05) [27.43]	22.77 (27.32) [21.96]	55.28 (64.05) [56.79]	42.23 (51.72) [46.41]	61.00 (67.80) [57.43]
WBI ⁶	1.483 (1.556) [1.560]	1.474 (1.550) [1.555]	1.754 (1.799) [1.779]	1.659 (1.714) [1.733]	1.581 (1.596) [1.637]

¹The charge density on the Al element.

²The charge density on the Sb element.

³ΔE_{ST} = E(triplet state for R—Al) − E(singlet state for R—Sb).

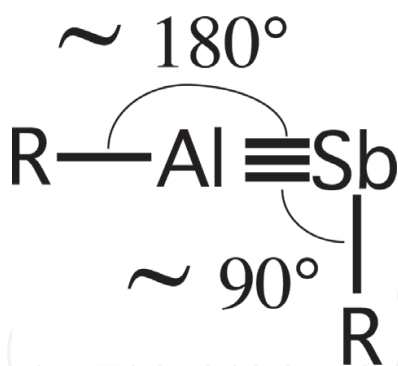
⁴ΔE_{ST} = E(triplet state for R—Al) − E(singlet state for R—Sb).

⁵BE = E(singlet state for R—Al) + E(triplet state for R—Sb) − E(singlet state for RAl≡SbR).

⁶The Wiberg bond index (WBI) for the Al≡Sb bond: see Ref. [22].

Table 1. The key geometrical parameters, the singlet-triplet energy splitting (ΔE_{ST}), the natural charge densities (Q_{Al} and Q_{Sb}), the binding energies (BE), the HOMO-LUMO energy gaps, and the Wiberg bond index (WBI) for RAl≡SbR using the M06-2X/Def2-TZVP, B3PW91/Def2-TZVP (in round brackets) and B3LYP/LANL2DZ + dp (in square brackets) levels of theory.

As seen in **Table 1**, the three DFT computational results predict that the Al≡Sb triple bond distance (Å) is in the ranges 2.388–2.539 (M06-2X/Def2-TZVP), 2.397–2.536 (B3PW91/Def2-TZVP) and 2.436–2.565 (B3LYP/LANL2DZ + dp). **Table 1** also shows that all of the geometrical



Scheme 2. The geometrical structure of RAl \equiv SbR with the small substituent, R.

structures of RAl \equiv SbR adopt the bent form, as demonstrated in **Scheme 2**. That is, $\angle\text{R}-\text{Al}-\text{Sb} \approx 180.0^\circ$ and $\angle\text{Al}-\text{Sb}-\text{R} \approx 90.0^\circ$. The reason for this vertical angle at the Sb center can be ascribed to the relativistic effect, as discussed previously [21]. The three DFT calculations shown in **Table 1** all indicate that the electronic ground states for R—Al and the R—Sb fragments are singlet and triplet, respectively. In particular, all of the DFT results shown in **Table 1** show that most of the singlet-triplet energy splitting (ΔE_{ST}) of R—Al is larger than that of the corresponding R—Sb. This strongly implies that the bonding characters of the triply bonded RAl \equiv SbR species that feature small substituents are better described by model [1], as shown in **Figure 1**. In other words, the triple bond consists of one donor-acceptor σ bond and two donor-acceptor π bonds, which are schematically represented as R—Al \equiv Sb—R. As previously mentioned, since the lone pair orbitals of both the R—Al and the R—Sb fragments feature the valence s character, their overlapping populations between the lone orbital and the valence p orbital should be smaller. Indeed, the supporting evidence from **Table 1** shows that all bond orders for the RAl \equiv SbR species are estimated to be less than 2.0 (WBI = 1.474–1.799), which is less than the bond order for the C \equiv C triple bond in acetylene (WBI = 2.99).

In brief, the three DFT calculations shown in this work show that irrespective of their electronegativity, the triply bonded RAl \equiv SbR molecules that feature small ligands are highly unlikely to exist, even in the low-temperature matrices. In particular, the bond orders of these Al \equiv Sb triple bonds are theoretically predicted to be a weak double bond, rather than a triple bond.

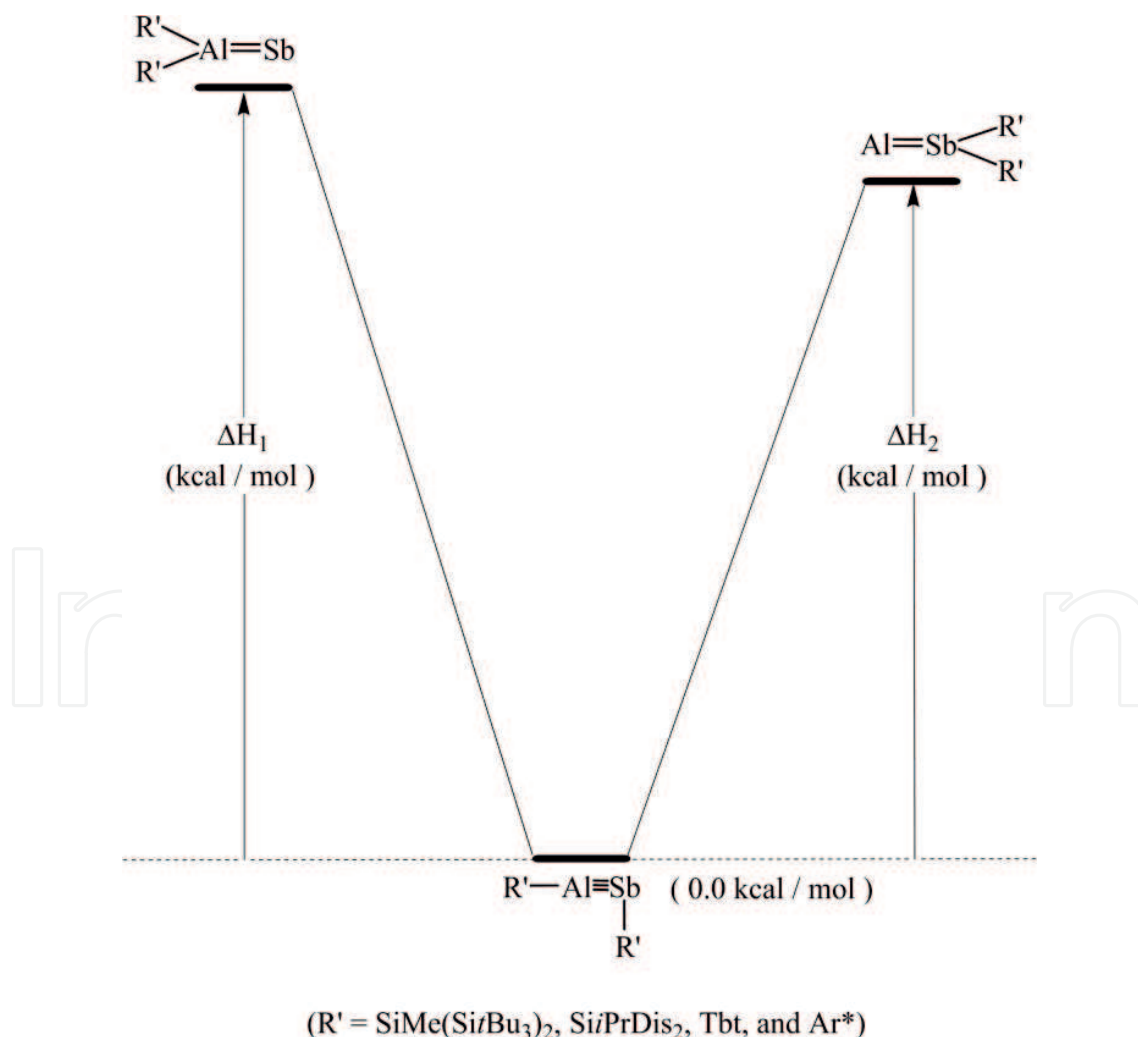
3.2. Large ligands on substituted R'Al \equiv SbR'

Three bulky groups were then used to search for kinetically stable triple-bonded R'Al \equiv SbR' molecules: R' (=SiMe(Si*t*Bu₃)₂, Si*i*PrDis₂, Tbt, and Ar*) [19]. These are shown in **Scheme 1**. It is known that London dispersion (nonvalent interactions) plays a prominent role in both chemical and physical properties of inorganic molecules [23]. As a result, the dispersion-corrected M06-2X/Def2-TZVP method is used in the present study to investigate the behaviors of the triply bonded R'Al \equiv SbR' compounds bearing bulky substituents. Similarly to the cases for small ligands on substituted RAl \equiv SbR, the dispersion-corrected M06-2X/Def2-TZVP level of theory is used to determine the potential energy surfaces for the intra-molecular 1,2-migration

reactions of $R'Al\equiv SbR'$, as shown in **Scheme 3**. The computed relative energies are listed in **Table 2**. The reaction enthalpies for both the 1,2-shift reactions ($R'Al\equiv SbR' \rightarrow R_2'Al=Sb$ and $R'Al\equiv SbR' \rightarrow R_2'Sb=Al$) are apparently too high. They are estimated to be at least 80 kcal/mol. The reason that both doubly bonded $R_2'Al=Sb$ and $R_2'Sb=Al$ isomers occupy such high energy points is simply because two bulky groups can cause steric overcrowding. As a consequence, the theoretical findings strongly suggest that the triply bonded $R'Al\equiv SbR'$, which is attached by two bulkier substituents, is kinetically stabilized.

Table 2 shows that the $Al\equiv Sb$ triple bond distance is predicted to be 2.422–2.477 Å. Since no experimental results for the $Al\equiv Sb$ triple bond length have been reported, these values are estimates. These theoretical calculations also show that the geometrical structures of $R'Al\equiv SbR'$ molecules that feature bulky groups adopt a bent structure; i.e., $\angle R'-Al-Sb \approx 160.0^\circ$ and $\angle Al-Sb-R' \approx 120.0^\circ$. As stated previously, the triply bonded $R'Al\equiv SbR'$ species feature this bent geometry because of the relativistic effect [23].

In addition, the bonding energy (BE) that is shown in **Table 2** shows that the central aluminum and antimony atoms in the substituted $R'Al\equiv SbR'$ compounds are strongly bonded, since the



Scheme 3. The qualitative potential energy surface of the $R'Al\equiv SbR'$ isomers with the bulky substituent, R' .

R'	SiMe(Si ^t Bu ₃) ₂	Si ⁱ PrDis ₂	Tbt	Ar*
Al≡Sb (Å)	2.463	2.422	2.477	2.447
∠R'—Al—Sb (°)	157.6	152.0	161.3	165.0
∠Al—Sb—R' (°)	126.5	123.6	122.2	124.6
∠R'—Al—Sb—R' (°)	173.5	172.9	167.2	166.0
Q _{Al} ¹	0.619	0.637	1.008	1.027
Q _{Sb} ²	−0.387	−0.492	−0.025	−0.114
ΔE _{ST} for Al—R' (kcal/mol) ³	28.89	27.30	42.50	40.21
ΔE _{ST} for Sb—R' (kcal/mol) ⁴	−16.89	−24.80	−30.51	−15.92
HOMO-LUMO (kcal/mol)	53.56	60.07	56.08	56.68
BE (kcal/mol) ⁵	71.29	72.97	87.43	74.33
ΔH ₁ (kcal/mol) ⁶	94.23	84.67	92.12	82.68
ΔH ₂ (kcal/mol) ⁶	83.15	84.08	80.01	88.19
WBI ⁷	2.174	2.181	2.072	2.016

¹The charge density on the Al element.

²The charge density on the Sb element.

³ΔE_{ST} (kcal mol^{−1}) = E(triplet state for R'—Al) − E(singlet state for R'—Al).

⁴ΔE_{ST} (kcal mol^{−1}) = E(triplet state for R'—Sb) − E(singlet state for R'—Sb).

⁵BE (kcal mol^{−1}) = E(triplet state for R'—Al) + E(triplet state for R'—Sb) − E(singlet for R'Al≡SbR').

⁶See **Scheme 3**.

⁷The Wiberg bond index (WBI) for the AlαSb bond: see Ref. [22].

See also **Scheme 3**.

Table 2. The key geometrical parameters, the singlet-triplet energy splitting (ΔE_{ST}), the natural charge densities (Q_{Al} and Q_{Sb}), the binding energies (BE), the HOMO-LUMO energy gaps, reaction enthalpies, and the Wiberg bond index (WBI) for R'Al≡SbR' at the dispersion-corrected M06-2X/Def2-TZVP level of theory.

BE values are in the range 71–97 kcal/mol for R' = SiMe(Si^tBu₃)₂, SiⁱPrDis₂, Tbt, and Ar*. **Table 2** also shows that the modulus ΔE_{ST} (kcal/mol) for Al—R' and Sb—R' fragments are predicted to be 43–27 and 31–16. These theoretical values allow two interpretations. Firstly, even when attached by bulkier groups, it is theoretically verified that both the Al—R' and the Sb—R' units occupy the ground singlet state and the ground triplet state, respectively. Since the ΔE_{ST} values for Al—R' are so small (compared with those for Al—R, as shown in **Table 1**), model [2] in **Figure 1** is most suitable to interpret the triple bonding characters in the R'Al≡SbR' species that feature bulky substituents. As schematically shown in **Figure 1**, the nature of the Al≡Sb triple bond can be considered as one conventional σ bond, one conventional π bond and one donor-acceptor π bond. That is, R'—Al≡Sb—R'. It is worthy of note that two factors affect the overlapping populations between the central Al and Sb elements. The first is that the lone pair orbital of the Sb—R' moiety features the valence s character. This, in turn, renders the overlap population between the pure p orbital of Al and the lone pair orbital of Sb very small. The other is that the sizes of the valence p orbitals for Al and Sb are quite different, since they belong to different rows of the periodic table having different principal quantum numbers. As a result, the triple bond in R'Al≡SbR' molecules that feature

bulky substituents is predicted to be quite weak. Indeed, the theoretical evidences given in **Table 2** shows that the bond order is a little bit higher than 2.0 (WBI \approx 2.17, 2.18, 2.07 and 2.02 for $R' = \text{SiMe}(\text{Si}t\text{Bu}_3)_2$, $\text{Si}i\text{PrDis}_2$, Tbt , and Ar^* , respectively). The bond order for the conventional $\text{C}\equiv\text{C}$ bond in acetylene is estimated to be 2.99.

Besides these, Dapprich and Frenking developed a useful method [24], which is called the introduced charge decomposition analysis (CDA), from which one may analyze donor-acceptor interactions of a A-B molecule. From CDA, one may obtain three parts. The first part is the number of electrons donated from the $R'-\text{Al}$ unit to the $R'-\text{Sb}$ monomer, which can be considered as $(R'-\text{Al}) \rightarrow (R'-\text{Sb})$. The second part is the number of electrons back donated from the $R'-\text{Sb}$ component to the $R'-\text{Al}$ moiety, which can be represented as $(R'-\text{Al}) \leftarrow (R'-\text{Sb})$. The third part is the repulsive interactions between $(R'-\text{Al})$ and $(R'-\text{Sb})$, which can be described as $(R'-\text{Al}) \leftrightarrow (R'-\text{Sb})$. The CDA results about the $(\text{SiMe}(\text{Si}t\text{Bu}_3)_2)\text{Al}\equiv\text{Sb}(\text{SiMe}(\text{Si}t\text{Bu}_3)_2)$ molecule based on the dispersion-corrected M06-2X/Def2-TZVP method are given in **Table 3**. As seen in **Table 3**, for the $(R'-\text{Sb})$ fragment, its largest contribution is No. 267 (HOMO) orbital, displaying that a $R'-\text{Sb}$ component donates electrons to a $R'-\text{Ga}$ unit mainly through the HOMO orbital. In consequence, the net amount of electron transfer is estimated to be -0.207 , implying that the $R'-\text{Sb}$ part donates more electrons to the $R'-\text{Al}$ moiety. This theoretical finding agrees well with the valence-electron bonding model shown in **Figure 1** (i.e., model [2]). Namely, the bonding character of $R'\text{Al}\equiv\text{Sb}R'$ can be recognized as $R'\text{Al}\rightleftharpoons\text{Sb}R'$.

	Orbital	Occupancy	A	B	A-B	W
	257	2.000000	0.000897	0.000398	0.000499	0.000052
	258	2.000000	-0.000691	-0.000223	-0.000469	-0.003158
	259	2.000000	0.000003	0.000212	-0.000209	-0.000135
	260	2.000000	-0.000574	0.001495	-0.002069	-0.003430
	261	2.000000	0.000322	0.000997	-0.000676	-0.003797
	262	2.000000	0.000333	0.000068	-0.002466	-0.012549
	263	2.000000	0.000927	0.007097	0.000859	0.000836
	264	2.000000	0.001417	0.031682	-0.003680	-0.003811
	265	2.000000	0.005618	0.033540	-0.057513	-0.129159
	266	2.000000	0.016174	0.031540	-0.017366	0.011841
HOMO	267	2.000000	-0.000521	0.063131	-0.032203	-0.047961
LUMO	268	0.000000	0.000000	0.000000	0.000000	0.000000
	269	0.000000	0.000000	0.000000	0.000000	0.000000
Sum ^a		534.000000	0.043071	0.250110	-0.207039	-0.099090

For clearness, only list the X, Y, and W terms for HOMO(no.267)-11 ~ LUMO+2.

^aSummation of contributions from all unoccupied and occupied orbitals.

Table 3. The charge decomposition analysis (CDA) for $R'\text{Al}\equiv\text{Sb}R'$ ($R' = \text{SiMe}(\text{Si}t\text{Bu}_3)_2$) system based on M06-2X orbitals, where a is the number of electrons donating from $R'-\text{Al}$ unit to $R'-\text{Sb}$ unit, B is the number of electrons donating from $R'-\text{Sb}$ moiety to $R'-\text{Al}$ moiety and W is the number of electrons involved in repulsive polarization.

The bonding characters of the Al≡Sb triple bond in R'Al≡SbR' molecules were examined using the natural bond orbital (NBO) [22] and the natural resonance theory (NRT) [25] analysis, whose results are given in **Table 4**, are used to determine the bonding properties. For instance, **Table 4** shows that for (SiMe(Si*t*Bu₃)₂)Al≡Sb(SiMe(Si*t*Bu₃)₂), the NBO model shows that the Al-Sb σ bonding orbital contains about 23% natural Al orbitals and 77% natural Sb orbitals. Also, the Al≡Sb π bonding orbital contains averagely about 25% natural Al orbitals and 75% natural Sb orbitals (**Figure 3**). These values give strong evidence that the Al≡Sb π bond is polarized. **Table 4** also shows that the Al≡Sb π bonding interaction: $\pi_{\perp}(\text{Al}\equiv\text{Sb}) = 0.529(3s3p^{1.98})\text{Al} + 0.849(5s5p^{12.43})\text{Sb}$ and $\pi_{\parallel}(\text{Al}\equiv\text{Sb}) = 0.475(3s3p^{99.99})\text{Al} + 0.880(5s5p^{99.99})\text{Sb}$, which again implies that the predominant bonding interaction between the Al—R and the Sb—R moieties originates from 3p(Al) ← 5p(Sb) donation. In other words, the electron deficiency on Al and the π bond polarity are partially balanced by the donation of the Sb lone pair to the empty Al p orbital (**Figure 3**). **Table 4** also shows that, on the basis of the NRT analyses of the electron density for (SiMe(Si*t*Bu₃)₂)Al≡Sb(SiMe(Si*t*Bu₃)₂), its Al≡Sb triple bond has a greater

R'Al≡SbR'	WBI	NBO analysis		NRT analysis		
		Occupancy	Hybridization	Polarization	Total/covalent/ionic	Resonance weight
R' = SiMe(Si <i>t</i> Bu ₃) ₂	2.17	σ: 1.91	σ: 0.4799 Al (sp ^{3.23}) + 0.8773 Sb (sp ^{0.60})	23.03% (Al) 76.97% (Sb)	2.06/1.25/0.81	Al—Sb: 10.84% Al=Sb: 71.95% Al≡Sb: 17.21%
		π _⊥ : 1.81	π _⊥ : 0.5288 Al (sp ^{1.98}) + 0.8487 Sb (sp ^{12.43})	27.96% (Al) 72.04% (Sb)		
		π _∥ : 1.89	π _∥ : 0.4753 Al (sp ^{99.99}) + 0.8798 Sb (sp ^{99.99})	22.59% (Al) 77.41% (Sb)		
R' = Si <i>i</i> PrDis ₂	2.18	σ: 1.91	σ: 0.5525 Al (sp ^{1.71}) + 0.8335 Sb (sp ^{1.15})	30.53% (Al) 69.47% (Sb)	2.48/1.29/1.19	Al—Sb: 10.63% Al=Sb: 75.53% Al≡Sb: 13.84%
		π _⊥ : 1.86	π _⊥ : 0.4723 Al (sp ^{3.67}) + 0.8815 Sb (sp ^{3.68})	22.30% (Al) 77.70% (Sb)		
		π _∥ : 1.89	π _∥ : 0.4476 Al (sp ^{99.99}) + 0.8943 Sb (sp ^{99.99})	20.03% (Al) 79.97% (Sb)		
R' = Tbt	2.07	σ: 1.95	σ: 0.6923 Al (sp ^{0.18}) + 0.7216 Sb (sp ^{12.38})	47.93% (Al) 52.07% (Sb)	2.22/1.41/0.82	Al—Sb: 5.89% Al=Sb: 65.89% Al≡Sb: 28.22%
		π _⊥ : 1.88	π _⊥ : 0.4488 Al (sp ^{47.14}) + 0.8936 Sb (sp ^{99.99})	20.14% (Al) 79.86% (Sb)		
		π _∥ : 1.91	π _∥ : 0.4772 Al (sp ^{99.99}) + 0.8788 Sb (sp ^{99.99})	22.78% (Al) 77.22% (Sb)		
R' = Ar*	2.02	σ: 1.96	σ: 0.6946 Al (sp ^{0.16}) + 0.7194 Sb (sp ^{18.14})	48.25% (Al) 51.75% (Sb)	2.01/1.44/0.57	Al—Sb: 11.37% Al=Sb: 76.76% Al≡Sb: 11.87%
		π _⊥ : 1.83	π _⊥ : 0.4543 Al (sp ^{99.99}) + 0.8908 Sb (sp ^{40.30})	20.64% (Al) 79.36% (Sb)		
		π _∥ : 1.92	π _∥ : 0.4266 Al (sp ^{99.99}) + 0.9044 Sb (sp ^{99.99})	18.20% (Al) 81.80% (Sb)		

Table 4. The natural bond orbital (NBO), the natural resonance theory (NRT) analysis, and Wiberg bond index (WBI) for R'Al≡SbR' molecules that feature ligands (R' = SiMe(Si*t*Bu₃)₂, Si*i*PrDis₂, and NHC) at the dispersion-corrected M06-2X/Def2-TZVP level of theory.

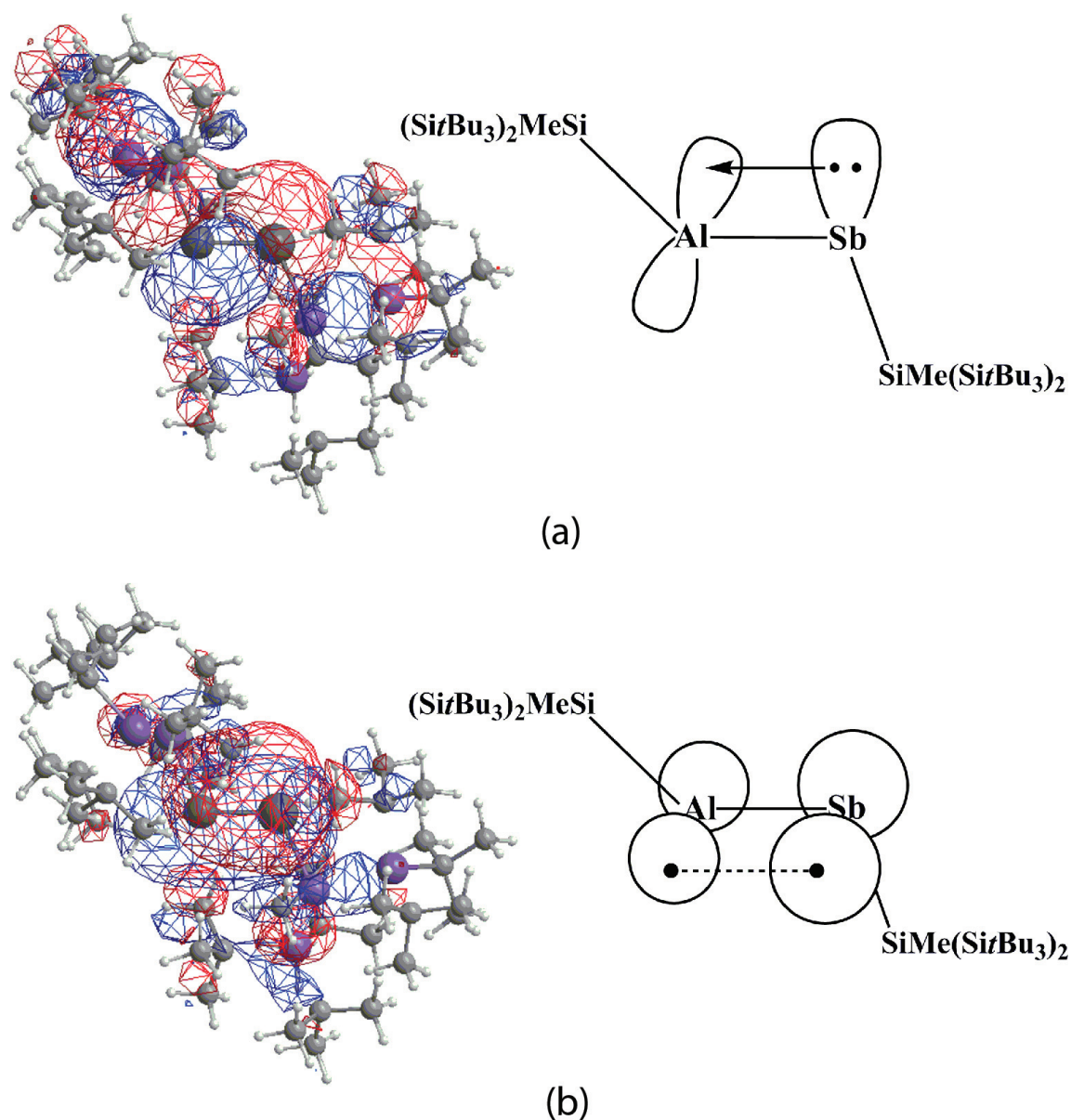


Figure 3. The natural $\text{Al}\equiv\text{Sb}$ π bonding orbitals ((i) and (ii)) for $(\text{SiMe}(\text{SiBu}_3)_2)\text{Al}\equiv\text{Sb}(\text{SiMe}(\text{SiBu}_3)_2)$. Also, see **Figure 1.** (i) π_{\perp} , (ii) π_{\parallel} .

covalent character, as shown by the greater covalent part of the NRT bond order (1.25), compared to its ionic part (0.81). The reason for this may be due to the fact that the difference between the electronegativity values for the Al and Sb elements is small (Al: 1.5 and Sb: 1.8) [26].

4. Conclusion

This study uses DFT computations to theoretically design substituted $\text{RAl}\equiv\text{SbR}$ molecules that feature the $\text{Al}\equiv\text{Sb}$ triple bond, that are stable from the kinetic viewpoint. The theoretical observations show that only bulky substituents (R') can significantly stabilize the triply

bonded R'Al \equiv SbR' compounds, and not small substituents. The theoretical findings also show that the bonding characters of the R'Al \equiv SbR' species that feature bulky groups can be represented as R'—Al \equiv Sb—R'. That is to say, the R'Al \equiv SbR' species contains a conventional σ bond, a conventional π bond and a donor-acceptor π bond. However, due to the poor overlapping populations between the Al and Sb elements, which is due to the different atomic sizes of the two elements and the nature of overlapping bonding orbitals, the Al \equiv Sb triple bond is very weak. The theoretical results also give strong evidence that the geometrical structures of the R'Al \equiv SbR' species adopt a bent conformation with a nearly perpendicular angle at the antimony center.

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